



Bipolar PNP Bare Die – BTP987

Part Description

The BTP987 is a general purpose PNP Darlington transistor supplied in bare die form.

Key Parameters:

- VCBO = -60V
- VCEO = -45V
- VEBO = -5V
- HFE = 2000 @ VCE = -10V, IC = -500mA
- VCE SAT = -1.3V @ IC = -0.5A, IB = -0.5mA
- fT = 200MHz @ VCE = -5V, IE = 0A
- COBO = -pF @ VCB = -V

Features

These high reliability transistors are suited for assembly on thick & thin-film hybrid circuits with high mechanical quality & Gold back metallization. Electrically they are characterized over temperature & supplied in multiple hirel grade options.

Die Size (Unawn)

680 μ m X 680 μ m, 27 Mils X 27 Mils

This is a shortform datasheet only

For the full datasheet

Please contact sales@siliconsupplies.com

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